



Dipartimento di
Ingegneria Civile e Ambientale

 POLITECNICO DI MILANO

Stochastic Effects on the Dynamics of a Resonant MEMS Magnetometer: a Monte Carlo Investigation

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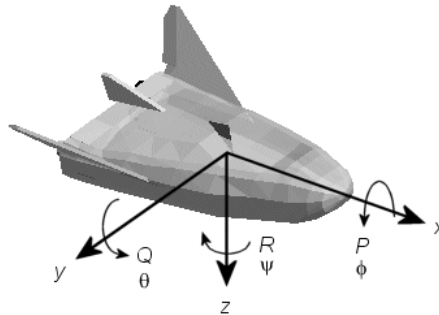
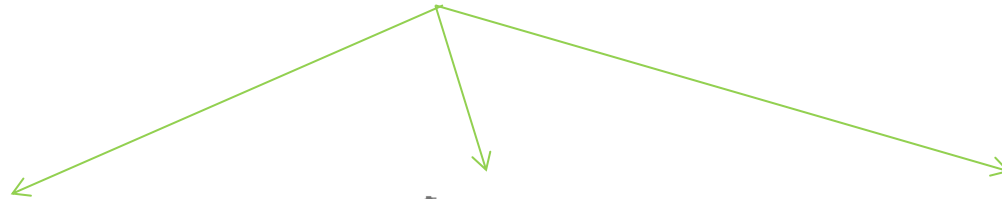
 International Electronic
Conference on Sensors and
Applications
1 - 16 June 2014

The earth magnetic field as a **vector** quantity

X, Y, Z components



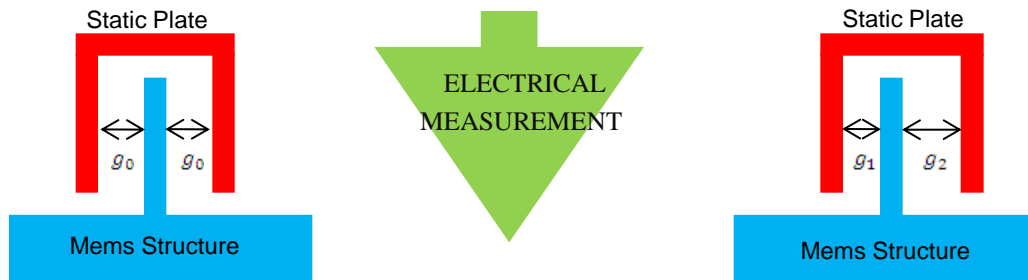
Orientation
determination



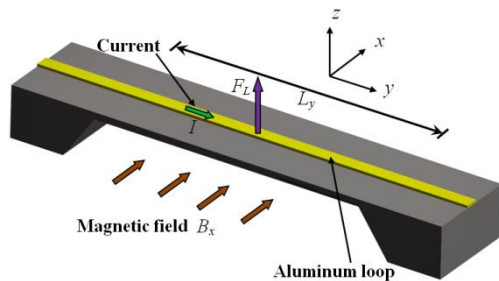
The external magnetic fields



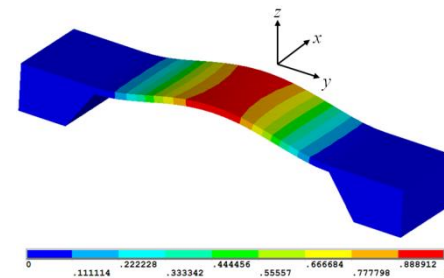
Change of the resonating system configuration (displacement, eigen-frequency)



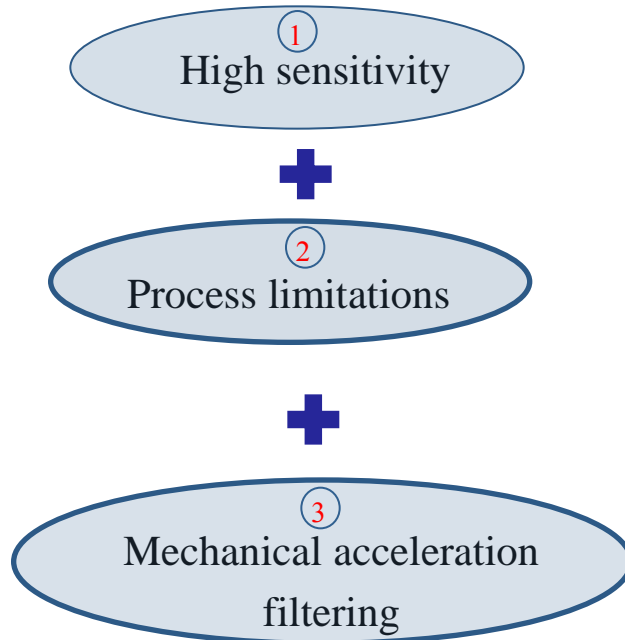
The magnetic field component is defined as a function of the configuration change



$$F_l = IB_x l_y$$

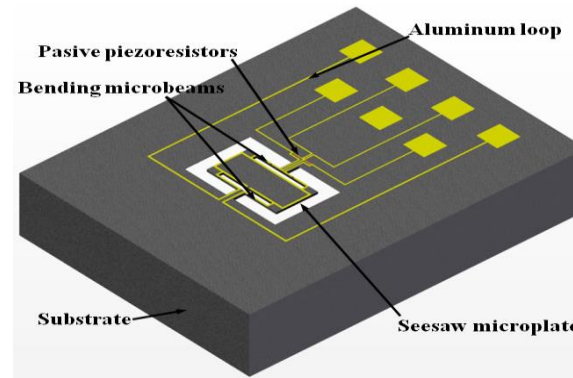


Design Demands

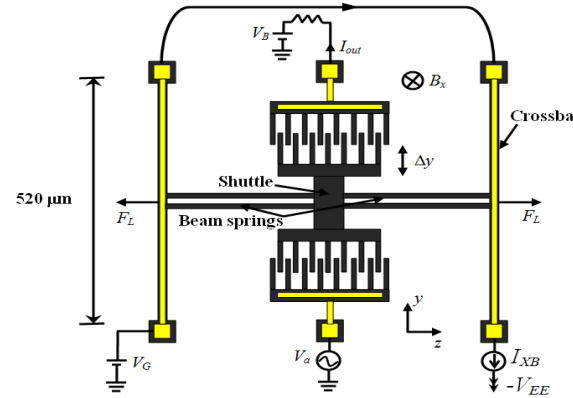


The goal of our designs

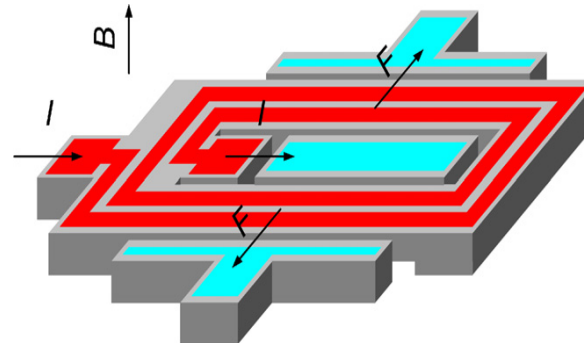
Some Designs In The Literature



Herrera-May et al

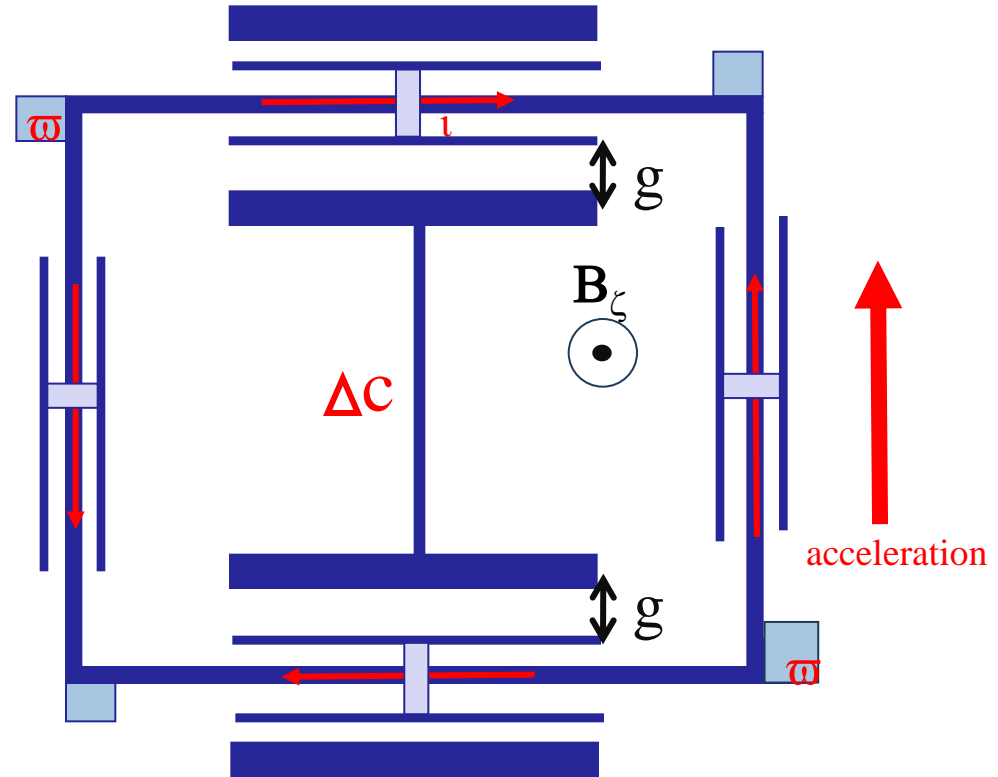
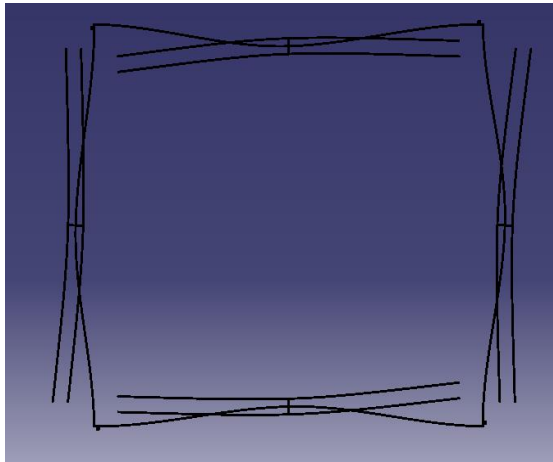


Behraad Bahreyni



VTT technical research center





d_m Displacement due to magnetic field

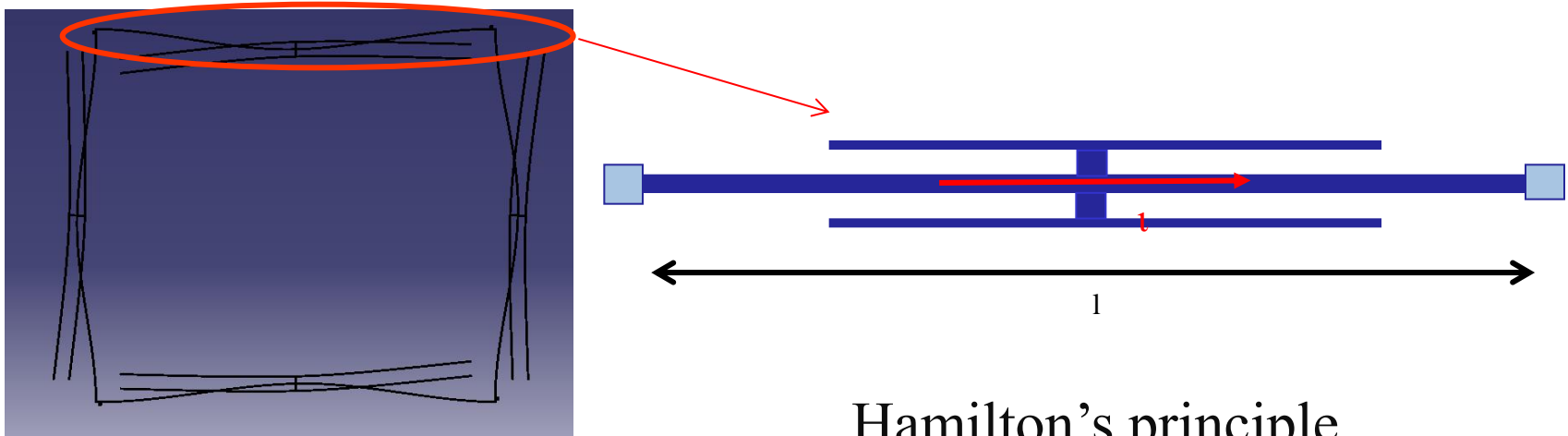
d_a Displacement due to acceleration

Absence of acceleration $\Delta c = f(+d_m + d_m)$

Presence of acceleration $\Delta c = f(+d_m + \cancel{d_a} - \cancel{d_a} + d_m)$

$\Delta c = f(2d_m)$

Mechanical acceleration
filtered out



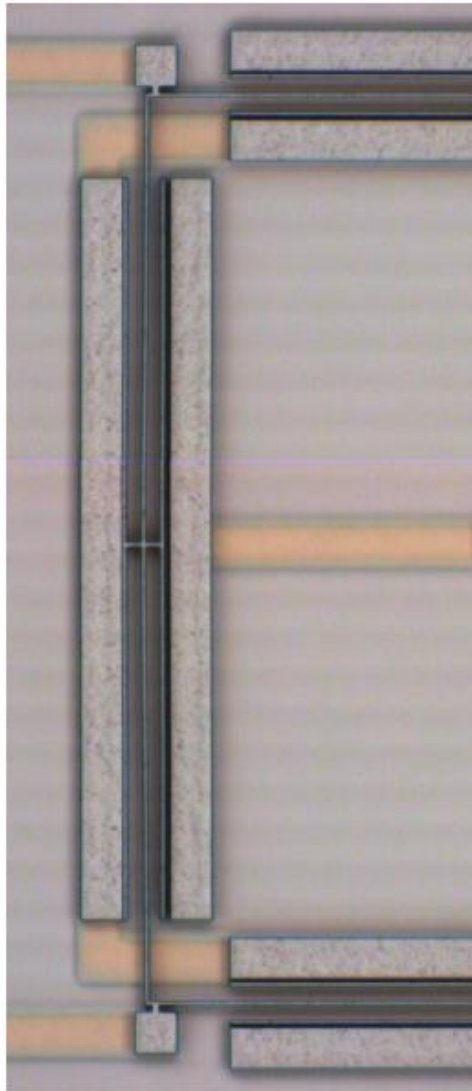
Hamilton's principle

$$m \frac{\partial^2 v}{\partial t^2} + c_d \frac{\partial v}{\partial t} + EI \frac{\partial^4 v}{\partial x^4} + p \frac{\partial^2 v}{\partial x^2} - \frac{EA}{2L} \frac{\partial^2 v}{\partial x^2} \int_0^L \left(\frac{\partial v}{\partial x} \right)^2 dx - F = 0$$

Thermo electro magneto mechanical problem

Joule effect

Lorentz force
and eddy current



Applying Galerkin method to
Hamilton's principle

First Eigen mode



$$\frac{d^2 q}{dt^2} + 2\mu \frac{dq}{dt} + \omega_0^2 q + Kq^3 = F_0 \cos \omega t$$

Clamped - Clamped



$$2\mu = \frac{c_d}{\rho A} \quad \omega_0^2 = \frac{16EI\pi^4}{3\rho A l^4} - \frac{E l \alpha_s \rho_e i^2 \pi^2}{9\rho A^2 k_H} \quad K = \frac{E\pi^4}{3\rho l^4} \quad F_0 = \frac{4iB_z}{3\rho A}$$

One degree of freedom equivalent system
(Duffing nonlinear equation)

$$\frac{d^2q}{dt^2} + 2\eta \frac{dq}{dt} + \omega_0^2 q + Kq^3 = F_0 \cos \omega t$$

Maximum amplitude of oscillation is given by the solution of

$$\left(\frac{F_0}{\omega_0^2}\right)^2 = \left(2\left(1 - \frac{\omega}{\omega_0}\right)Z_{MAX} + \frac{3K}{4\omega_0^2}Z_{MAX}^3\right)^2 + \left(\frac{2\mu}{\omega_0}Z_{MAX}\right)^2$$

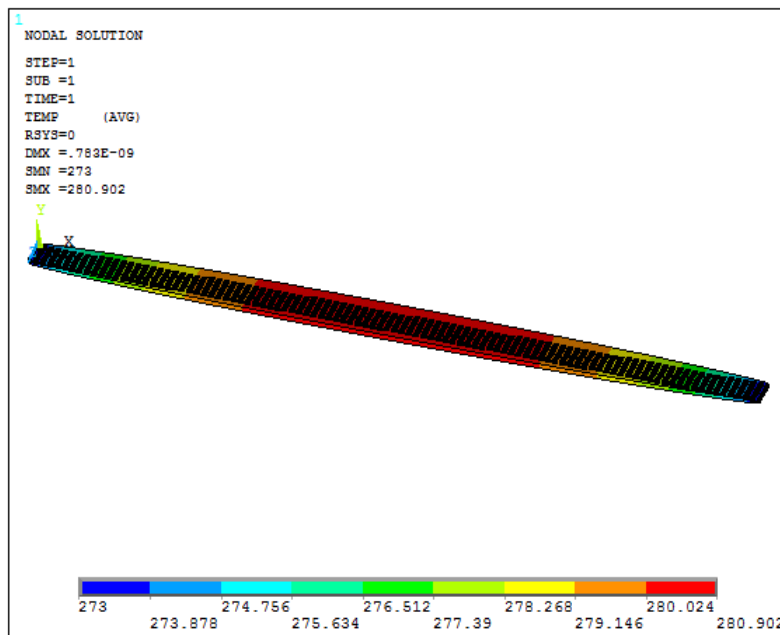
Current frequency $\omega = \omega_0$



$$Z_{Max} = \left[\left(\left(\frac{64F_0^4}{81K^4} + \frac{262144\mu^6\omega_0^6}{19683K^6} \right)^{\frac{1}{2}} + \frac{8F_0^2}{9K^2} \right)^{\frac{1}{3}} - \frac{64\mu^2\omega_0^2}{27K^2 \left(\left(\frac{64F_0^4}{81K^4} + \frac{262144\mu^6\omega_0^6}{19683K^6} \right)^{\frac{1}{2}} + \frac{8F_0^2}{9K^2} \right)^{\frac{1}{3}}} \right]^{\frac{1}{2}}$$

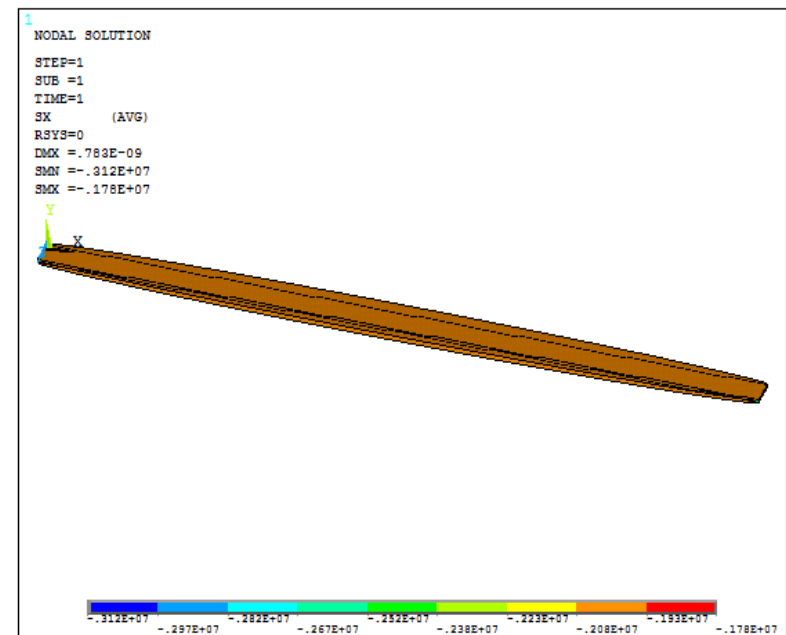
To check the model, Ansys multi-physics simulations were performed

Static thermo-electro-structural analysis



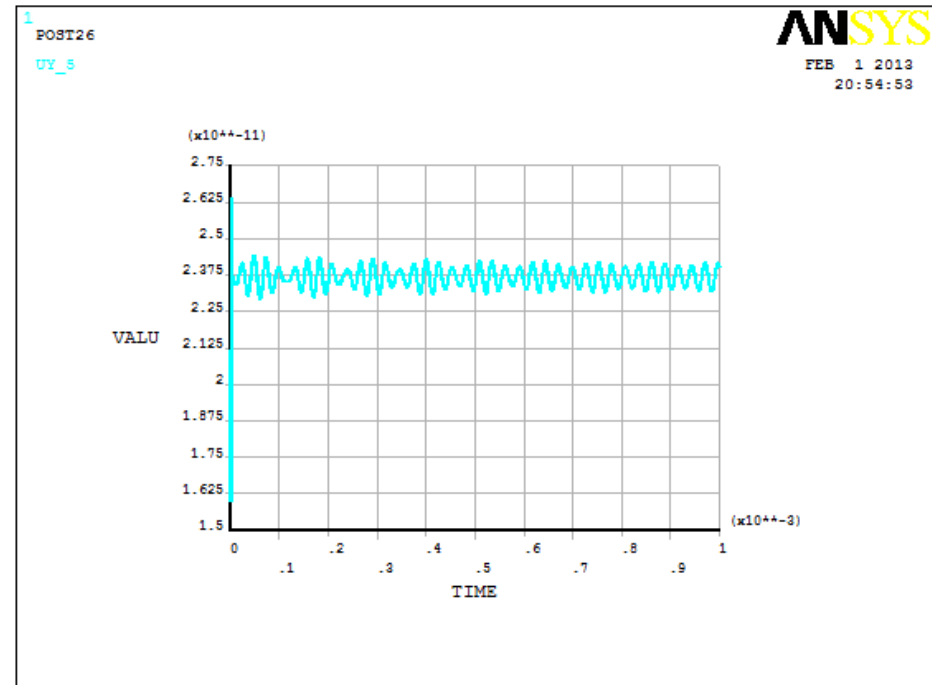
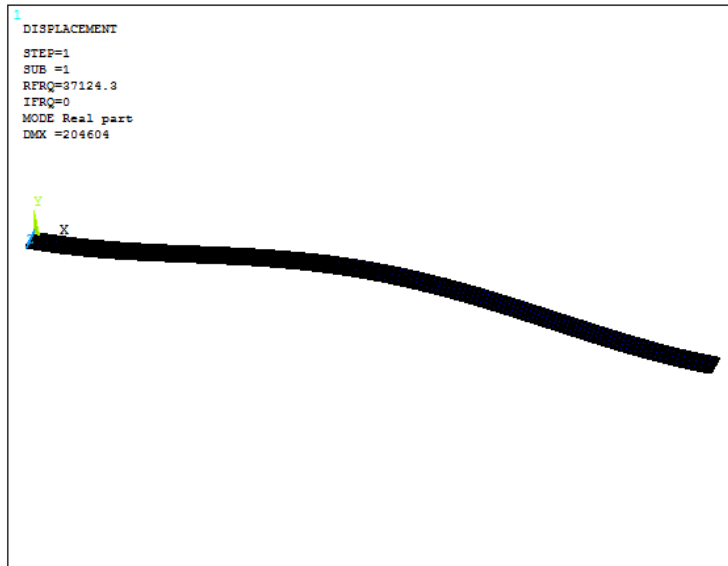
Temperature field:

$$T_{Max} = 280.90 \text{ (Ansys)}$$
$$280.90 \text{ (Analytical)}$$



Stress field:

$$\sigma_{th} = -1.9756E + 06 \text{ Pa (Ansys)}$$
$$-1.9757E + 06 \text{ Pa (Analytical)}$$



Prestressed modal analysis:

$$f = 37124 \text{ Hz (Ansys)}$$
$$37334 \text{ Hz (Analytical)}$$

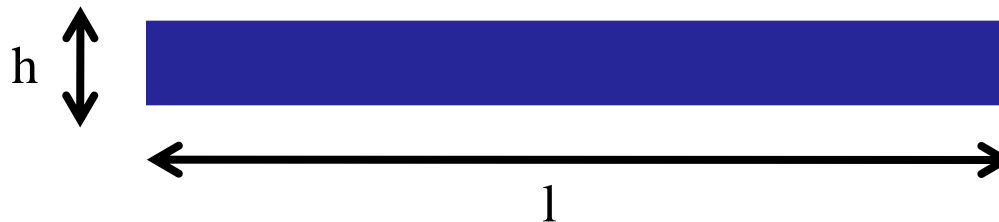
$$\max_{Dis_{midpoint}} = 2.41e - 11 \text{ (Ansys)}$$
$$2.36e - 11 \text{ (Analytical)}$$

Sensor's performance

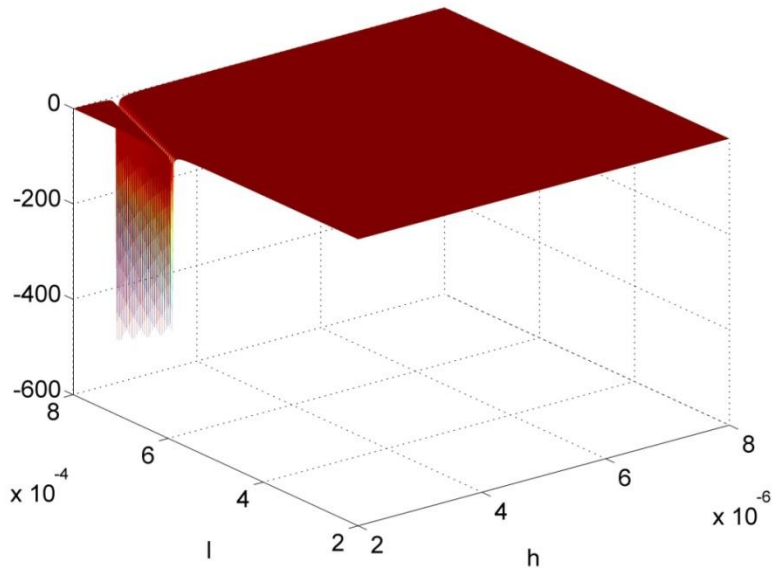
Sensitivity (Maximum amplitude)

Power consumption (Minimum electrical resistance)

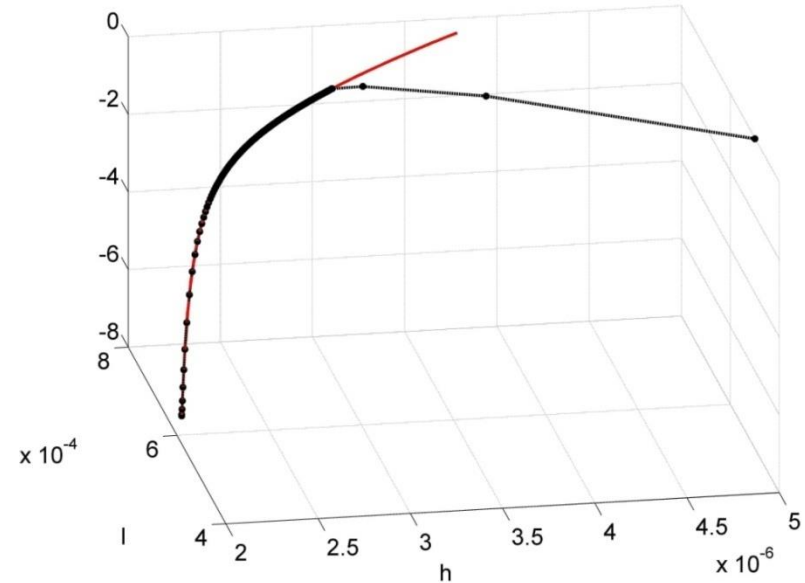
To have an optimal device, we perform a multi objective optimization procedure, consisting of a structural objective function (Z_{Max}) and an electrical objective function (R_{elec})



Optimal h, l of the multi-physics solution
for the fundamental component



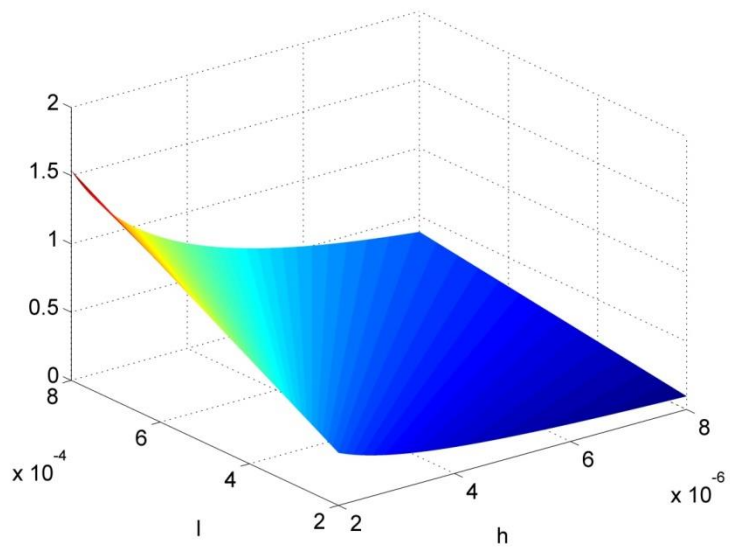
Unconstrained objective function



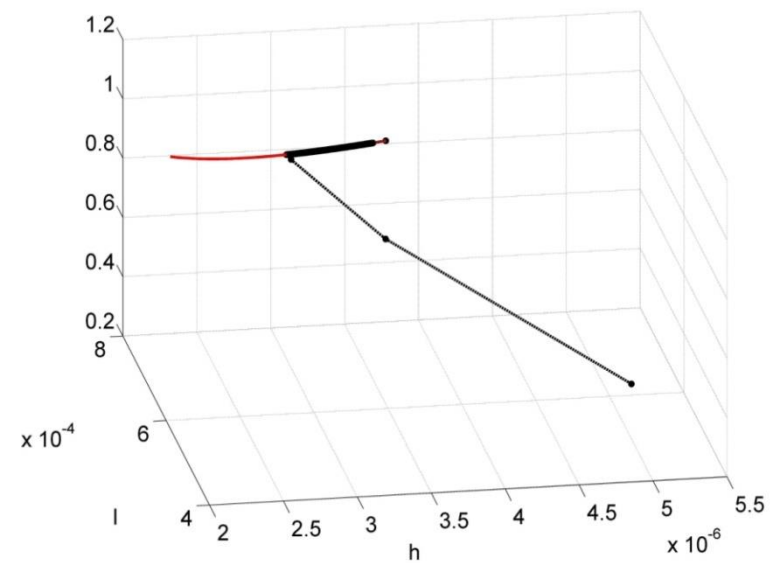
Constrained objective function (red line), and optimal path followed by the minimization algorithm (black dotted line)

Except for the first iterations that move from a point violating the prescribed equality constraint, the optimizer provides a set of feasible solutions to the arising sub-problems.

It finally ends with the expected global minimum $h=2\mu\text{m}$, $l=580.9\mu\text{m}$



Unconstrained objective function



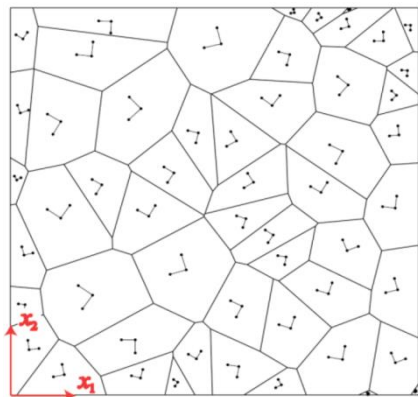
Constrained objective function (red line), and optimal path followed by the minimization algorithm (black dotted line)

Except for the first iterations that move from a point violating the prescribed equality constraint, the optimizer provides a set of feasible solutions to the arising sub-problems.

It finally ends with the expected global minimum $h=3.8\mu\text{m}$, $l=798.1\mu\text{m}$

Sources of uncertainty in the model and probability density functions (PDFs)

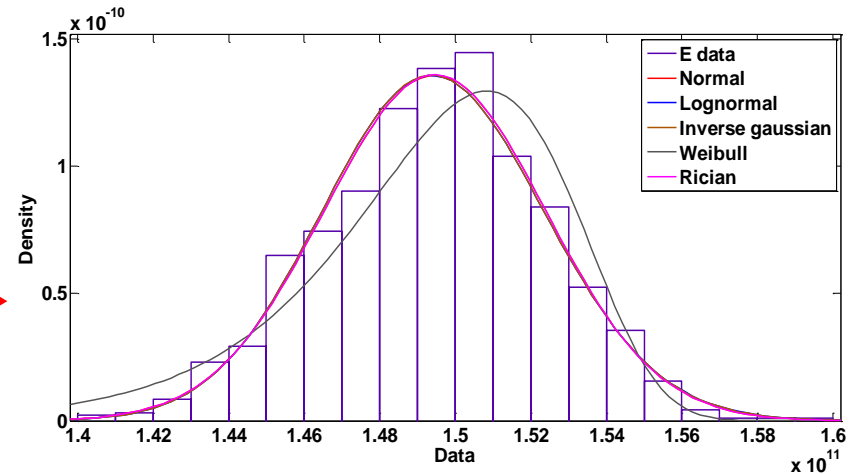
Young's modulus



RVE of polysilicon

E distribution

Maximum likelihood

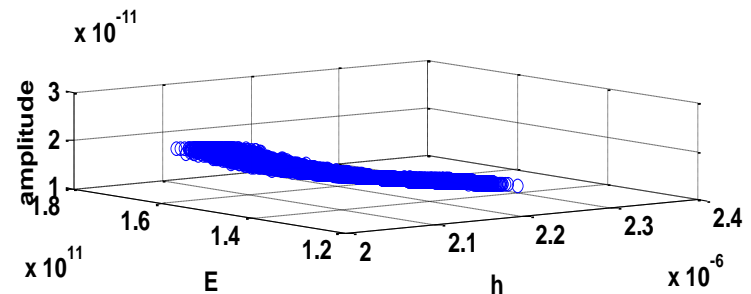
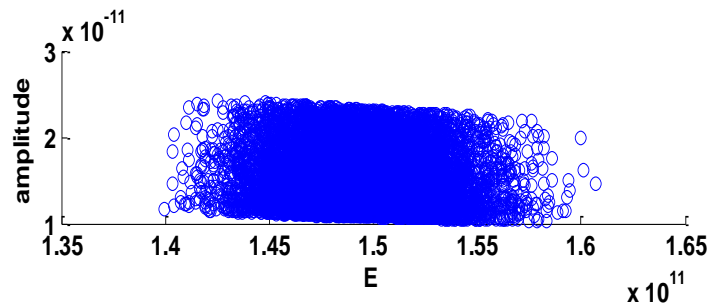
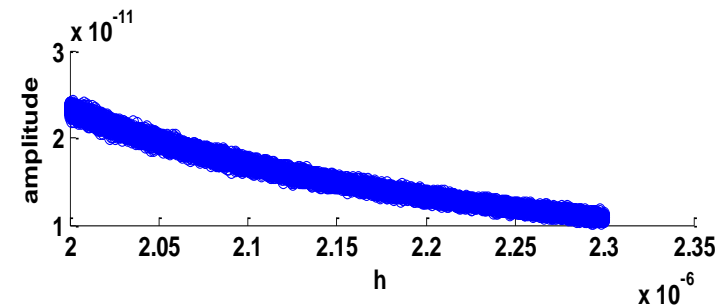
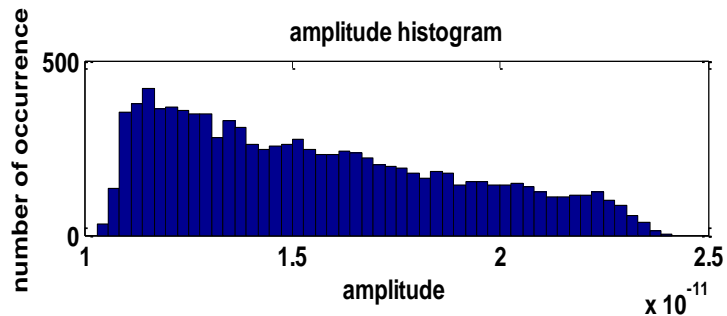
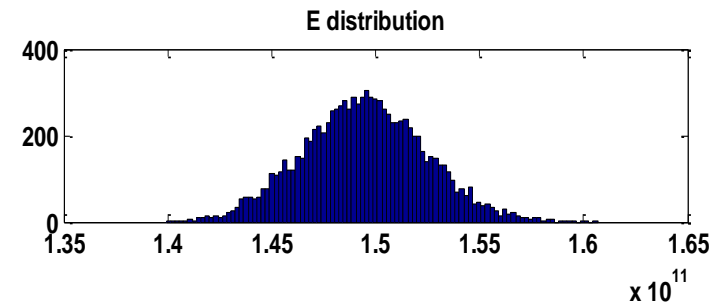
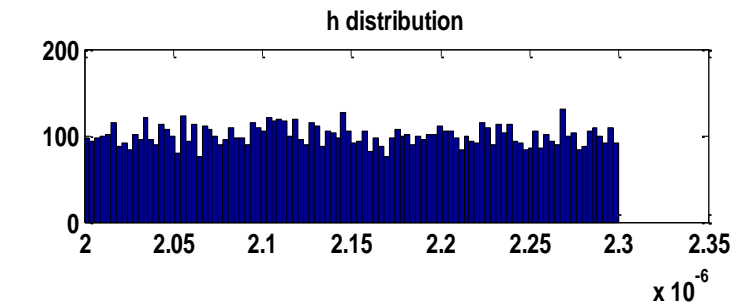


PDF of E

Over etching

uncertainty in beam width due to process (uniform PDF)

Monte Carlo simulation: effect of uncertainties on Z_{Max} around the optimal values



- ❖ Validate the multi-physics model by a commercial FEM code (either Ansys or Comsol)
- ❖ Adopt a topology optimization approach to find the optimal shape of the base component (to search for the optimal shape, not only beam shaped structures, but also tapered, curved and any other arbitrary shape)
- ❖ Performing the experimental tests on the devices